

GPA030A135MN-FDR

GPA030A135MN-FDR Information



For Reference Only

Part Number GPA030A135MN-FDR

Manufacturer Global Power Technologies Group

Category Discrete Semiconductor Products
Transistors - IGBTs - Single

Description IGBT 1350V 60A 329W TO3PN

Package TO-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









GPA030A135MN-FDR Specifications

Manufacturer Part Number	GPA030A135MN-FDR
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-3
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	1350V
Current - Collector (Ic) (Max)	60A
Current - Collector Pulsed (Icm)	90A
Vce(on) (Max) @ Vge, Ic	2.4V @ 15V, 30A
Power - Max	329W
Switching Energy	4.4mJ (on), 1.18mJ (off)
Input Type	Standard
Gate Charge	300nC
Td (on/off) @ 25°C	30ns/145ns
Test Condition	600V, 30A, 5 Ohm, 15V
Reverse Recovery Time (trr)	450ns
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-3
Supplier Device Package	TO-3PN
	Report errors?

GPA030A135MN-FDR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

GPA030A135MN-FDR Payment Methods



















GPA030A135MN-FDR Shipping Methods













If you have any question about GPA030A135MN-FDR, please do not hesitate to contact us!

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